Video IF Amplifier for Multistandard TV and VTR

Technology: Bipolar

Features

- Standard B/G-L suitable, processes negatively and positively modulated IF-signals with equal polarity of the output signal
- Ultra white inverter and ultra black limiter for reduc-• ing transmission interference
- Internally noise protected gain control, no flyback . pulses required
- Expanded video frequency response allows the demodulation of amplitude modulated MAC signals

- High input sensitivity
- Fast AGC by controlled discharge of the AGC capacitor

Standard L mode: AGC acting on peak white level, capacitor discharge control by averaged video signal

Standard B/G: AGC acting on the sync. pulse peak

The direction of the AFC curve is selectable indepen-• dently from the standard switch

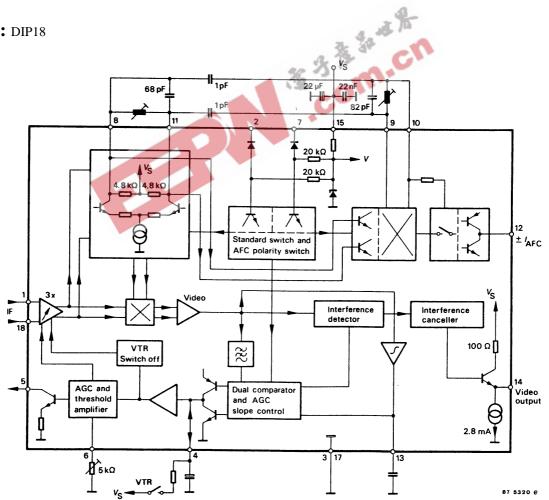
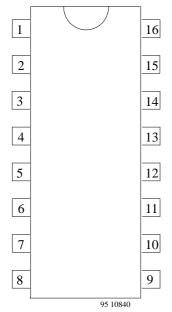


Figure 1. Block diagram

Case: DIP18

TDA4439

Pin Description



Pin	Function						
1, 18	IF input						
2	Standard switch: open B/G						
	ground L						
3, 17	Ground						
4	IF-AGC storage capacitor						
5	AGC (tuner control)						
6	Tuner AGC take over						
7	Polarity switch:						
	open AFC "DOWN"						
	ground AFC "UP"						
8, 11	Demodulator circuit						
9, 10	AFC circuit						
12	AFC output						
13	Average capacitor standard L						
14	Video output						
15	Supply voltage						
16	n.c.						
2 The second							

Circuit Description

The following function units are integrated in this circuit combination for video-IF processing:

- Three symmetric, highly stable, gain controlled wideband amplifier, quasi galvanic coupling eliminates feed back
- Video carrier controlled demodulator of high linearity
- Polarity switch over for video and AFC-signal
- Video output amplifier with low-pass characteristics, limiter for ultra black and inverter for ultra white interference

Disconnectable AFC – generator with push pull current output

High impedance, interference free controlled voltage facilities, best possible AGC time constant with small storage capacitor

- Controlled discharge circuit for fast gain control
- With VTR operation the video output level is according to the ultra white level in B/G, ultra black level in L

Absolute Maximum Ratings

Reference point pin 3, unless otherwise specified

Parameters	Symbol	Value	Unit	
Supply voltage	Pin 15	VS	10 to 15	V
Supply current	Pin 15	IS	75	mA
Open loop voltage	Pin 5	V ₅	V _S	V
External voltage	Pin 4	V4	10	V
	Pin 14	V ₁₄	8	V
Breaking current for VTR operation	I ₄	0.5	mA	
Video output current				
max load	Pin 14	Io	5	mA
short circuit max 1 s	Pin 14		50	
Power dissipation $T_{amb} \le 60^{\circ}$	P _{tot}	1.0	W	
Junction temperature		T _i	125	°C
Ambient temperature range	T _{amb}	-25 to +70	°C	
Storage temperature range	T _{stg}	-25 to +125	°C	

Thermal Resistance

Parameters	Symbol	Maximum	Unit
Junction ambient	R _{thJA}	60	K/W

Electrical Characteristics

 $V_S = 12 V$, $T_{amb} = 25^{\circ}C$, Reference point Pin 3, unless otherwise specified

Test Conditio	ns / Pins	Symbol	Min	Typ	Max	Unit
			141111.		Iviax.	mA
	rm 15	15		0.5		IIIA
	Pin 14	Vo	48	52	56	v
	1	•0	1.0	5.2	5.0	•
	Pin 14	Vo	1.75	1.9	2.05	v
Peak to peak	Pin 14	v ₀	2.7	3.0	3.3	V
Peak to peak	Pin 14	v ₀	1.85	2.1	2.35	V
			1.5	5		
	Pin 14	Δ	2.2	~	10	%
		27				
	Pin 14	V ₁₄	25	0 mV belo	w Sync. (ty	p.)
		-0				
	Pin 14	V ₁₄	900 mV	/ upper ultr	a white leve	el (typ.)
	Pin 14	V ₁₄		3.6		V
	Pin 14	Δ		0.5		%/V
	Dim 14			1.0		%/V
-5 dB	Pin 14	B _{video}		10		MHz
	Pin 1/	$\Lambda V \rightarrow 0$			2.0	dB
V = 9 V				2.8	2.0	mA
$v_{14} - 8 v$	Pin 14	114		2.0		
	Din 1	+			10	
+			2			μs V
+						V V
-20V	r III Z	v ₂	0		1.2	v
$V_{4} = 0.8 V$	Pin 1_18	v		120		μV
• 4 - 0.0 v	1 III 1-10		60	120		dB
+		Δvp	00			uD
	Pin 5	١-	3	4		mA
+	1	1 3	5			
	Pin 5	AGC		61		dB
	Peak to peak	Peak to peak Pin 14 Pin 14 Pin 14 Pin 12 Pin 2 Pin 2 Pin 2 V14=3.0 Vpp, Pin 1-18 Pin 5 Pin 5	Pin 15 Is Pin 14 v_0 Pin 14 v_0 Pin 14 v_0 Peak to peak Pin 14 v_0 Pin 14 Δ v_14 Pin 14 V_{14} V_{14} Pin 14 V_{14} V_{14} Pin 14 V_{14} V_{14} Pin 14 Δ Δ $V_{14} = 8 V$ Pin 14 Δ Pin 2 V_2 V_1 Pin 2 V_2 ∇ $V_14 = 3.0 V_{pp}$ Δ Δ Pin 5 I_5 Δ	Pin 15 Is Pin 14 v_0 4.8 Pin 14 v_0 1.75 Peak to peak Pin 14 v_0 2.7 Peak to peak Pin 14 v_0 1.85 Pin 14 v_0 1.85 Pin 14 Δ 1.85 Pin 14 Δ 25 Pin 14 Δ 900 mV Pin 14 V_{14} 900 mV Pin 14 V_{14} 900 mV Pin 14 V_{14} 900 mV Pin 14 Δ_{14} 900 mV Pin 14 V_{14} 900 mV Pin 14 V_{14} 900 mV Pin 14 V_{14} 900 mV Pin 14 Δ_{14} 900 mV	Pin 15 Is 65 Pin 14 v_0 4.8 5.2 Pin 14 v_0 1.75 1.9 Peak to peak Pin 14 v_0 2.7 3.0 Peak to peak Pin 14 v_0 1.85 2.1 Pin 14 v_0 1.85 2.1 Pin 14 Δ 1.85 2.1 Pin 14 Δ 900 mV upper ultr Pin 14 V_{14} 900 mV upper ultr Pin 14 V_{14} 3.6 Pin 14 Δ 0.5 Pin 14 ∇_1 2.8 Pin 2 ∇_2 2 Pin 2 ∇_2 0	Pin 15 Is 65 Pin 14 v_0 4.8 5.2 5.6 Pin 14 v_0 1.75 1.9 2.05 Peak to peak Pin 14 v_0 2.7 3.0 3.3 Peak to peak Pin 14 v_0 1.85 2.1 2.35 Pin 14 Δ 10 1.85 2.1 2.35 Pin 14 Δ 10 10 10 Pin 14 Δ 10 250 mV below Sync. (type) 10 Pin 14 V_{14} 900 mV upper ultra white level 10 Pin 14 Δ 0.5 10 Pin 14 Δ 0.5 10 Pin 14 Δ 1.0 2.0 V14 = 8 V Pin 14 I14 2.8 Pin 4 tr 10 10 Pin 2 V2 2 V5 Pin 2 V2 0 1.2 V14= 3.0 Vpp, Vp 60 <t< td=""></t<>

TDA4439

TELEFUNKEN Semiconductors

TEMIC

Parameters	Test Conditions / Pins	Symbol	Min.	Тур.	Max.	Unit
IF-residual voltage at the	f = 38.9 MHz Pin 14	v		10		mV
video output in the AGC	f = 77.8 MHz Pin 14			20		
area						
Differential gain error	Pin 14	d		3	5	%
Differential phase error	Pin 14	φ		3	5	degree
Sound-chroma beat (1.07	Video carrier = 0 dB	α _{IM}		50		dB
MHz intermodulation) relat-	Pin 14					
ing to demodulated auxiliary	Colour carrier = -6 dB					
colour carrier	Sound carrier = -24 dB					
Upsetting factor sync. pulse		$\frac{\varDelta V_{sync}}{V_{sync}}$		3		%
Input impedance	Pin 1–18	R _i		1.6		kΩ
	Pin 1–18	Ċi		2		pF
Switch OFF voltage for						
VTR-operation	Pin 4	V_4	8		10	V
Switch OFF current for						
VTR-operation	Pin 4	I_4			150	μΑ
DC voltage at the						
AFC circuit	Pins 9 and 10	V		5.0		V
Scope of the AFC voltage	Pin 12	V	1.0	5. /m	V _S -1.5	V
AFC current	Pin 12	i ₁₂	X	0.8		mA
AFC transconductance	Pin 12	g		0.2		<u>mA</u> 100kHz
AFC residual current (AFC "OFF")	$V_{12} = V_S/2$ Pin 12	±I _R	;0.		10	μΑ
AFC current – OFF	Pins 9 and 10	IOFF	100	150		μΑ
AFC polarity switching volt- age ⁷⁾	"AFC-up" Pin 7 "AFC-down"	V ₇	0 2		1.2 Vs	V

1)

2)

All measurements Pin 14 without load Residual carrier 10 $\%^{3}$, Blanking level 30 % carrier amplitude A peak white value for at least 10 μ s must be transmitted for each complete frame 4)

5) Direct control of standard reversing switch with TTL level

6) Sync peak value standard B/G

7) AFC polarity switch may be directly matched to TTL-output (i.e. processor output)

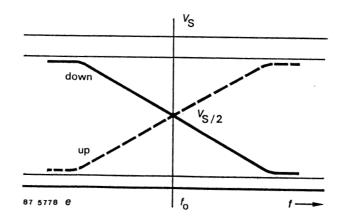
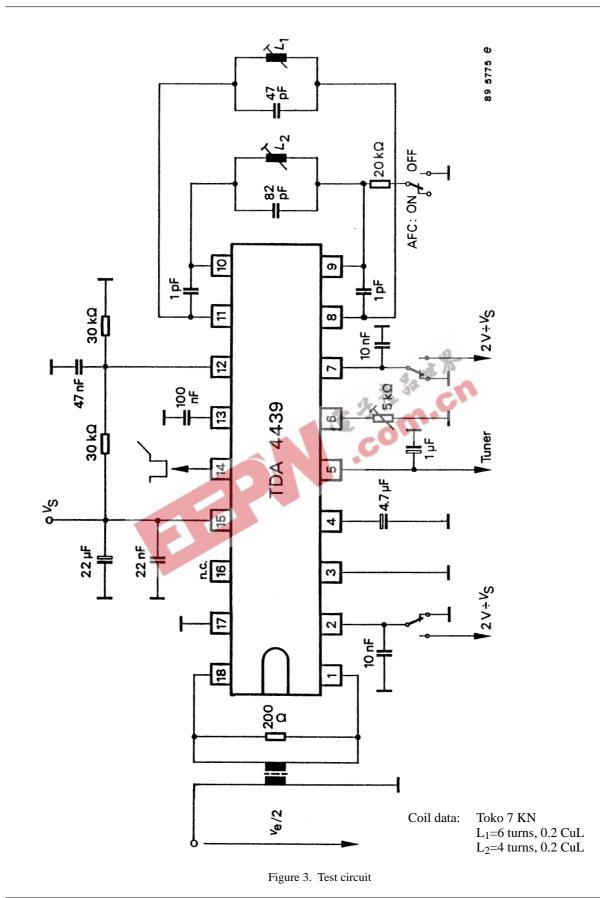


Figure 2. AFC characteristics/polarity

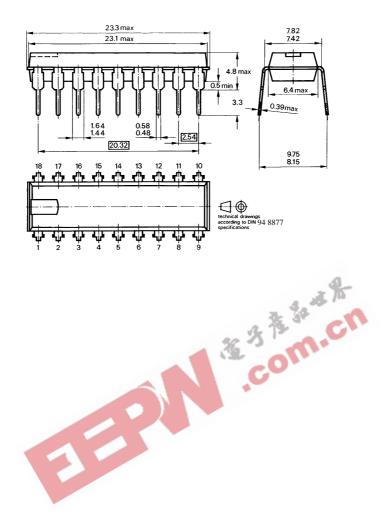
TEMIC TELEFUNKEN Semiconductors





Dimensions in mm

Package: DIP 16



Ozone Depleting Substances Policy Statement

It is the policy of TEMIC TELEFUNKEN microelectronic GmbH to

- 1. Meet all present and future national and international statutory requirements.
- 2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

TEMIC TELEFUNKEN microelectronic GmbH semiconductor division has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

TEMIC can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design and may do so without further notice. Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use TEMIC products for any unintended or unauthorized application, the buyer shall indemnify TEMIC against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

TEMIC TELEFUNKEN microelectronic GmbH, P.O.B. 3535, D-74025 Heilbronn, Germany Telephone: 49 (0)7131 67 2831, Fax number: 49 (0)7131 67 2423